

# STTH3010

## Ultrafast recovery - high voltage diode

### Main product characteristics

I <sub>F(AV)</sub>	30 A
V <sub>RRM</sub>	1000 V
Тj	175° C
V <sub>F</sub> (typ)	1.30 V
t <sub>rr</sub> (typ)	42 ns

## Features and benefits

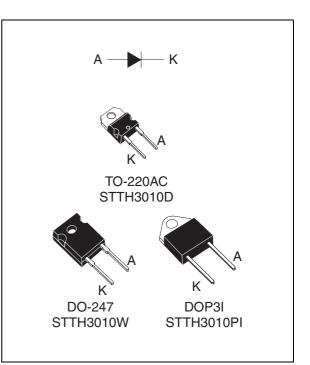
- Ultrafast, soft recovery
- Very low conduction and switching losses
- High frequency and/or high pulsed current operation
- High reverse voltage capability
- High junction temperature
- Insulated package:
  - DOP3I Electrical insulation = 2500 V<sub>RMS</sub> Capacitance = 12 pF

## Description

The high quality design of this diode has produced a device with low leakage current, regularly reproducible characteristics and intrinsic ruggedness. These characteristics make it ideal for heavy duty applications that demand long term reliability.

Such demanding applications include industrial power supplies, motor control, and similar mission-critical systems that require rectification and freewheeling. These diodes also fit into auxiliary functions such as snubber, bootstrap, and demagnetization applications.

The improved performance in low leakage current, and therefore thermal runaway guard band, is an immediate competitive advantage for this device.



## Order codes

Part Number	Marking
STTH3010D	STTH3010D
STTH3010W	STTH3010W
STTH3010PI	STTH3010PI

# 1 Characteristics

### Table 1. Absolute ratings (limiting values at 25° C, unless otherwise specified)

Symbol	Pa		Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse voltage	Repetitive peak reverse voltage			
I <sub>F(RMS)</sub>	RMS forward current	RMS forward current			
	TO-220 / DO-247 $T_c = 105^{\circ} C$				А
IF(AV)	Average forward current, $\delta = 0.5$ DOP3I $T_c = 65^{\circ} C$				A
I <sub>FRM</sub>	Repetitive peak forward current	$t_p = 5 \ \mu s$ , F = 5 kHz square		300	А
I <sub>FSM</sub>	Surge non repetitive forward current t <sub>p</sub> = 10 ms Sinusoidal			180	А
T <sub>stg</sub>	Storage temperature range				°C
Тj	Maximum operating junction tempera	ture		175	°C

### Table 2.Thermal parameters

Symbol	Para	Value	Unit	
<b>B</b>	lunction to case	TO-220 / DO-247	1.1	°C/W
' 'th(j-c)	R <sub>th(j-c)</sub> Junction to case		1.8	0/11

### Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I <sub>B</sub> <sup>(1)</sup>	Reverse leakage current	$T_j = 25^\circ C$	V <sub>R</sub> = V <sub>RRM</sub>			15	μA
'R` ´	neverse leakage current	T <sub>j</sub> = 125° C	VR − VRRM		10	100	μΛ
		$T_j = 25^\circ C$				2	
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 100° C	I <sub>F</sub> = 30 A		1.4	1.8	V
		$T_j = 150^\circ C$			1.3	1.7	

1. Pulse test:  $t_p$  = 5 ms,  $\delta$  < 2 %

2. Pulse test: t<sub>p</sub> = 380  $\mu$ s,  $\delta$  < 2 %

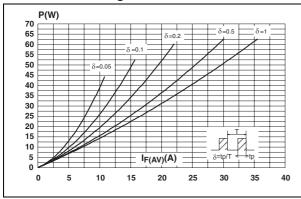
To evaluate the conduction losses use the following equation: P = 1.3 x  $I_{F(AV)}$  + 0.013  ${I_F}^2_{(RMS)}$ 

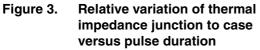


Table 4. Dynamic charac	cteristics	
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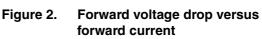
Symbol	Parameter	Test conditions	Min.	Тур	Max.	Unit
		$\label{eq:IF} \begin{array}{l} I_F = 1 \ A, \ dI_F/dt = \text{-50 } A/\mus, \\ V_R = 30 \ V, \ T_j = 25^\circ \ C \end{array}$			100	
t <sub>rr</sub>	Reverse recovery time	$I_F = 1 \text{ A}, dI_F/dt = -100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}, T_j = 25^{\circ} \text{ C}$		53	70	ns
		$\label{eq:IF} \begin{array}{l} I_{F} = 1 \ A, \ dI_{F}/dt = \text{-200 } A/\mus, \\ V_{R} = 30 \ V, \ T_{j} = 25^{\circ} \ C \end{array}$		42	55	
I <sub>RM</sub>	Reverse recovery current	$    I_F = 30 \text{ A}, \ dI_F/dt = -200 \text{ A}/\mu \text{s}, \\ V_R = 600 \text{ V}, \ T_j = 125^\circ \text{ C} $		24	32	А
S	Softness factor	$    I_F = 30 \text{ A}, \text{ dI}_F/\text{dt} = -200 \text{ A}/\mu\text{s}, \\    V_R = 600 \text{ V}, \text{ T}_j = 125^\circ \text{ C} $		1		
t <sub>fr</sub>	Forward recovery time	$I_F = 30 \text{ A} \qquad dI_F/dt = 100 \text{ A}/\mu\text{s}$ $V_{FR} = 1.5 \text{ x} \text{ V}_{Fmax},   \text{T}_\text{j} = 25^\circ \text{ C}$			450	ns
V <sub>FP</sub>	Forward recovery voltage	$I_F = 30 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s},$ $T_j = 25^\circ \text{ C}$		5		V

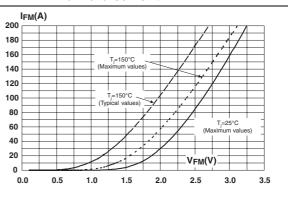
# Figure 1. Conduction losses versus average current

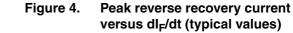


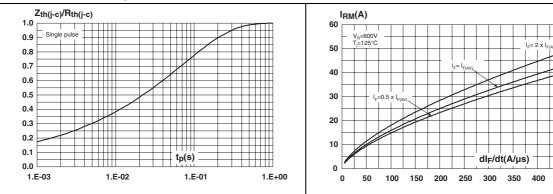


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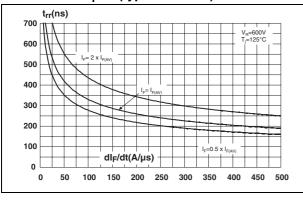






450 500

### Figure 5. Reverse recovery time versus dl<sub>F</sub>/dt (typical values)



### Figure 7. Softness factor versus dl<sub>F</sub>/dt (typical values)

### Figure 6. Reverse recovery charges versus dl<sub>F</sub>/dt (typical values)

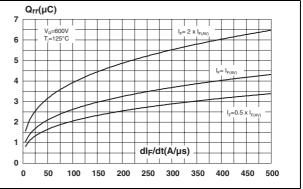
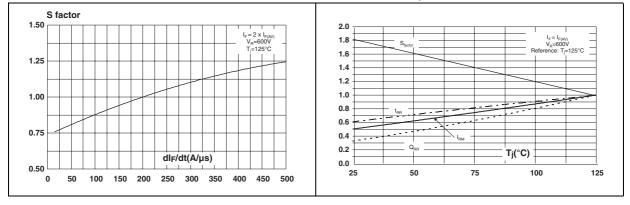
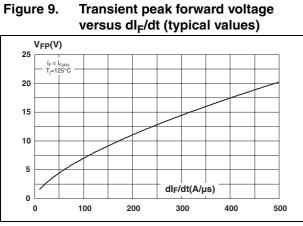


Figure 8. Relative variations of dynamic parameters versus junction temperature







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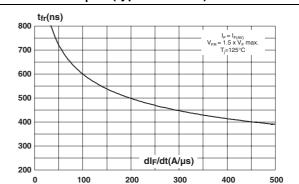
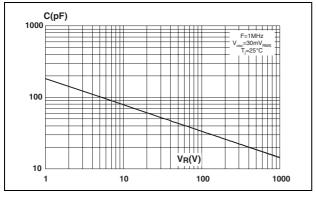


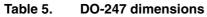
Figure 11. Junction capacitance versus reverse voltage applied (typical values)





## 2 Package information

Epoxy meets UL94, V0 Cooling method: by conduction (C) Recommended torque value: 0.55 Nm (TO-220AC) Recommended torque value: 0.80 Nm (SOD93, DOP31, and DO-247) Maximum torque value: 0.7 Nm (TO-220AC) Maximum torque value: 1.0 Nm (SOD93, DOP31, and DO-247)



				DIMEN	SIONS		
	REF.	М	illimete	rs		Inches	
		Min.		Max	Min.		Max.
	Α	4.85		5.15	0.191		0.203
	D	2.20		2.60	0.086		0.102
	E	0.40		0.80	0.015		0.031
	F	1.00		1.40	0.039		0.055
	F2		2.00			0.078	
	F3	2.00		2.40	0.078		0.094
	G		10.90			0.429	
	Н	15.45		15.75	0.608		0.620
L2	L	19.85		20.15	0.781		0.793
	L1	3.70		4.30	0.145		0.169
L3 $V_2$ $\downarrow$	L2		18.50			0.728	
	L3	14.20		14.80	0.559		0.582
M E	L4		34.60			1.362	
	L5		5.50			0.216	
	М	2.00		3.00	0.078		0.118
	V		5°			5°	
	V2		60°			60°	
	Dia.	3.55		3.65	0.139		0.143



				DIMEN	SIONS	
		REF.	Millim	neters	Inc	hes
			Min.	Max.	Min.	Max.
		А	4.40	4.60	0.173	0.181
H2	A	С	1.23	1.32	0.048	0.051
		D	2.40	2.72	0.094	0.107
	L7	E	0.49	0.70	0.019	0.027
		F	0.61	0.88	0.024	0.034
		F1	1.14	1.70	0.044	0.066
	D	G	4.95	5.15	0.194	0.202
		H2	10.00	10.40	0.393	0.409
L4		L2	16.40 typ.		0.645 typ.	
F→← ↓	M	L4	13.00	14.00	0.511	0.551
le le	→ E	L5	2.65	2.95	0.104	0.116
G		L6	15.25	15.75	0.600	0.620
		L7	6.20	6.60	0.244	0.259
		L9	3.50	3.93	0.137	0.154
		М	2.6	typ.	0.102	2 typ.
		Diam. I	3.75	3.85	0.147	0.151

Table 6. T0-220AC dimensions



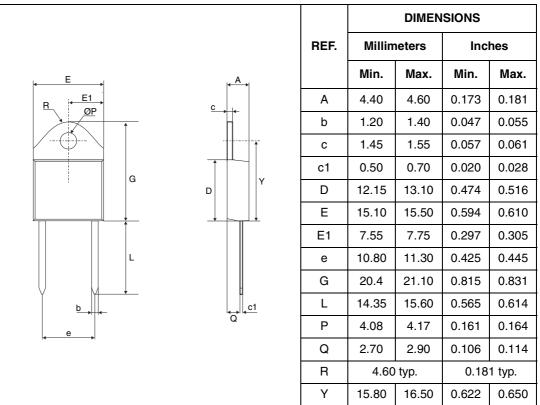


Table 7.DOP3I dimensions

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



# **3** Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
STTH3010D	STTH3010D	TO-220AC	1.86 g	50	Tube
STTH3010PI	STTH3010PI	DOP3I	4.46 g	30	Tube
STTH3010W	STTH3010W	DO-247	4.4 g	30	Tube

# 4 Revision history

D	ate	Revision	Description of Changes
02-Ma	ar-2006	1	First issue.



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